TOSHIBA Intelligent Power Module Silicon N Channel IGBT

MIG100Q201H

High Power Switching Applications

Motor Control Applications

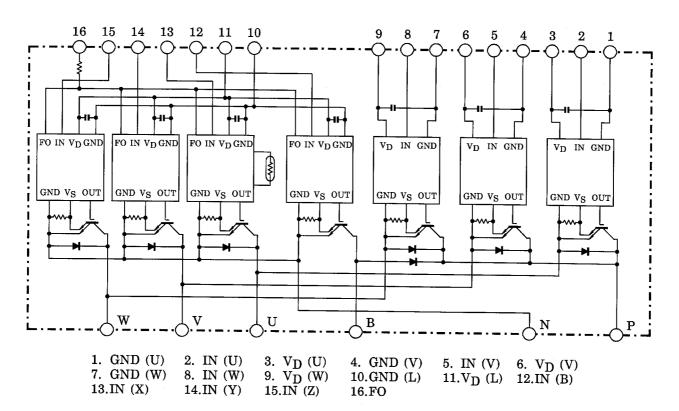
- Integrates inverter, brake power circuits & control circuits (IGBT drive units, protection units for over-current, under-voltage & over-temperature) in one package.
- The electrodes are isolated from case.
- High speed type IGBT : V_{CE} (sat) = 3.5 V (Max.)

t_{off} = 2.5 μs (Max.)

 $t_{rr} = 0.21 \ \mu s$ (Max.)

- Outline : TOSHIBA 2-136A1A
- Weight:

Equivalent Circuit



Maximum Ratings (T_j = 25°C)

Stage	Characteristic	Condition	Symbol	Ratings	Unit
	Supply voltage	P-N power terminal	V _{CC}	900	V
	Collector-emitter voltage	—	V _{CES}	1200	V
Inverter	Collector current	T _c = 25°C, DC	Ι _C	100	А
Inverter	Forward current	T _c = 25°C, DC	١ _F	100	А
	Collector power dissipation	T _c = 25°C	P _C	800	W
	Junction temperature	—	Tj	150	°C
	Supply voltage	P-N power terminal	V _{CC}	900	V
Brake	Collector-emitter voltage	—	V _{CES}	1200	V
	Collector current	T _c = 25°C, DC	Ι _C	50	А
	Reverse voltage	—	V _R	1200	V
	Forward current	T _c = 25°C, DC	١ _F	50	А
	Collector power dissipation	T _c = 25°C	P _C	400	W
	Junction temperature	—	Tj	150	°C
	Control supply voltage	V _D -GND terminal	VD	20	V
Control	Input voltage	IN-GND terminal	V _{IN}	20	V
Control	Fault output voltage	FO-GND (L) terminal	V _{FO}	20	V
	Fault output current	FO sink current	I _{FO}	14	mA
Module	Operating temperature	—	TC	-20 ~ +100	°C
	Storage temperature range	—	T _{stg}	-40 ~ +125	°C
	Isolation voltage	AC 1 minute	V _{ISO}	2500	V
	Screw torque	M5	—	3	N∙m

Electrical Characteristics ($T_j = 25^{\circ}C$)

a. Inverter Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	lony	V _{CE} = 1200 V	T _j = 25°C	_	_	1	mA
	ICEX		T _j = 125°C	_	_	20	
Collector-emitter saturation		V_D = 15 V, I _C = 100 A V _{IN} = 3 V \rightarrow 0 V	T _j = 25°C		2.7	3.5	v
voltage	V _{CE (sat)}	$V_{IN} = 3 V \rightarrow 0 V$	T _j = 125°C	_	2.6		v
Forward voltage	V _F	I _F = 100 A		_	2.0	2.7	V
	t _{on}	$\begin{array}{l} V_{CC} = 600 \text{ V}, \text{ I}_{C} = 100 \text{ A} \\ V_{D} = 15 \text{ V}, \text{ V}_{\text{IN}} = 3 \text{ V} &\leftrightarrow 0 \text{ V} \\ \text{Inductive load} \\ & (\text{Note 1}) \end{array}$		0.8	1.5	2.2	
	t _{o(on)}			_	0.5	1.0	
Switching time	t _{rr}				0.14	0.21	μs
	t _{off}			_	1.5	2.5	
	t _{c(off)}			_	0.3	0.6	

b. Brake Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	losy	$\lambda_{1} = -1200\lambda_{1}$	T _j = 25°C	_	—	1	mA
	ICEX	V _{CE} = 1200V	T _j = 125°C		_	20	ША
Collector-emitter saturation voltage		V _D = 15V, I _C = 50A	T _j = 25°C	_	2.7	3.5	v
Conector-emitter saturation voltage	V _{CE (sat)}	V _D = 15V, I _C = 50A V _{IN} = 3V→0V	T _j = 125°C	_	2.6	_	v
Reverse current	I _R	V _R = 1200V	T _j = 25°C	_	—	1	mA
			T _j = 125°C	_	—	20	ША
Forward voltage	VF	I _F = 50A		_	2.0	2.7	V
	t _{on}	$V_{CC} = 600V, I_C = 50A$ $V_D = 15V, V_{IN} = 3V \leftrightarrow 0V$ Inductive load (Note 1)		0.8	1.5	2.2	-
	t _{c(on)}				0.5	1.0	
Switching time	t _{rr}				0.30	0.45	μs
	t _{off}			_	1.5	2.5	
	t _{c(off)}]		_	0.3	0.6	

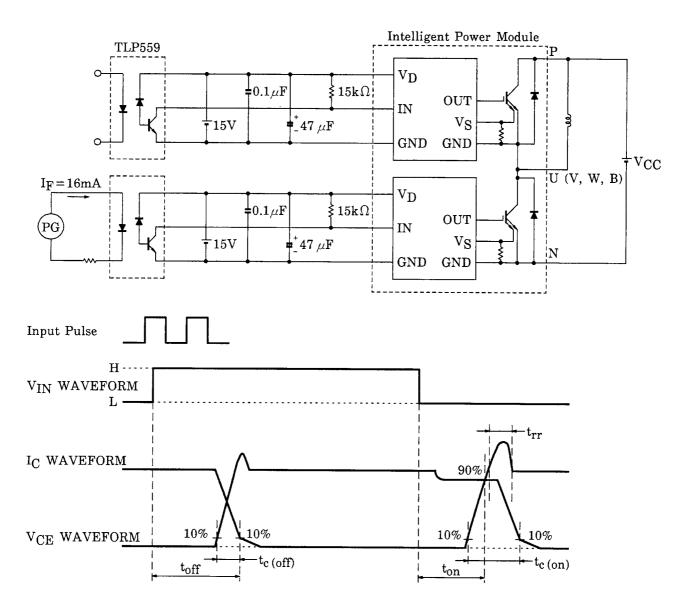
c. Control Stage (T_j = 25°C)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Control circuit	High side	I _{D (H)}	- V _D = 15 V	_	20	30	mA
current	Low side	I _{D (L)}		_	80	120	ШA
Input-on signal voltage		V _{IN (on)}	V _D = 15 V, I _C = 100 mA	0.9	1.1	1.3	V
Fault output current	Protection	I _{FO (on)}	– V _D = 15 V	8	10	12	mA
	Normal	I _{FO (off)}	- VD = 15 V	_	_	1	
Over current protection trip level	Inverter		OC V _D = 15 V, T _j = 125°C	160	200	—	A
	Brake	- 00		70	100	_	
Short current	Inverter			240	300	—	A
protection trip level	Brake	- SC	V _D = 15 V, T _j = 125°C	105	150	_	
Over current cut-off	time	t _{off (OC)}	V _D = 15 V	_	10	—	μs
Over	Trip level	ОТ		111	118	125	°C
temperature protection	Reset level	OTr	Case temperature	93	100	107	с С
Control supply under voltage protection	Trip level	UV		11.3	12.0	12.7	N
	Reset level	UVr	7 –	11.8	12.5	13.2	V
Fault output pulse width		t _{FO}	V _D = 15 V	1	2	3	ms

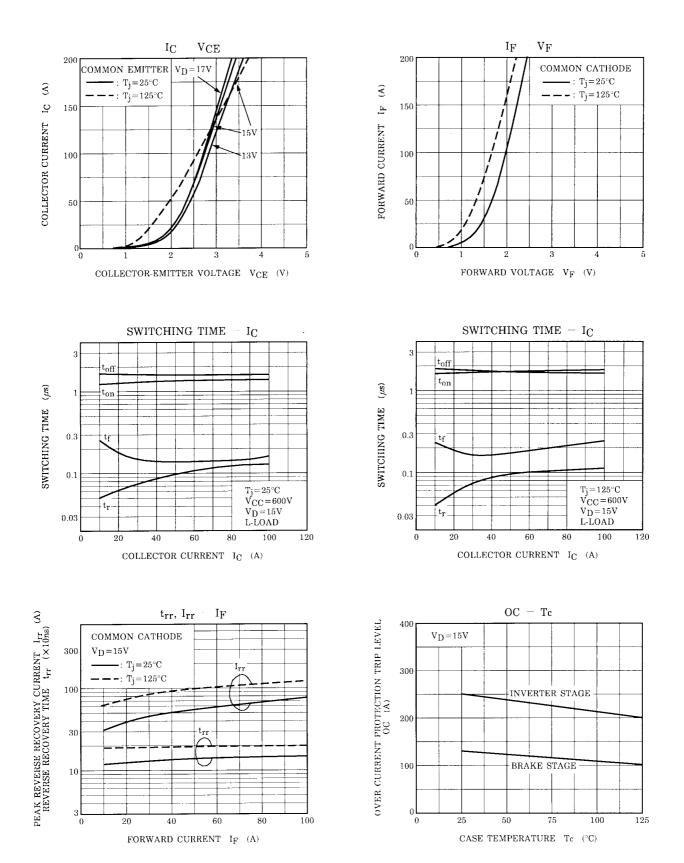
d. Thermal Resistance (T_j = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	l resistance R _{th (j-c)}	Inverter IGBT	_	_	0.156	°C/W
Junction to case thermal resistance		Inverter FRD	_	_	0.50	
Junction to case thermal resistance		Brake IGBT			0.312	
		Brake FRD	_	_	1.00	
Case to fin thermal resistance	R _{th (c-f)}	Compound is applied	_	0.04	—	°C/W

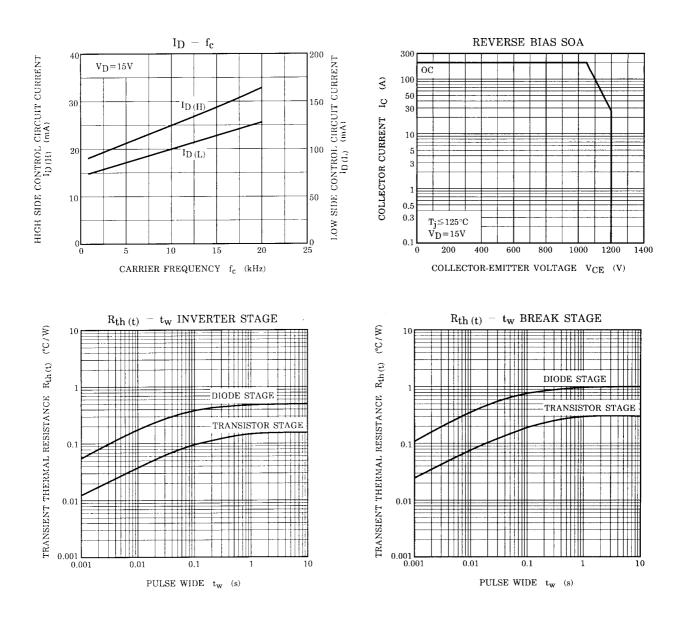
Note 1 : Switching time test circuit & timing chart



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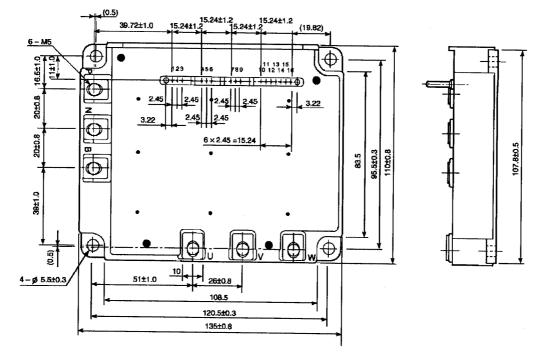


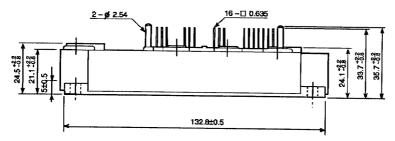
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Package Dimensions: TOSHIBA 2-136A1A

Unit: mm





1. GND (U)	2. IN (U)	3. V _D (U)	4. GND (V)	5. IN (V)	6 VD (V)
7. GND (W)	8. IN (W)			$11.V_{\rm D}$ (L)	
13.IN (X)	14.IN (Y)	15.IN (Z)	16.FO	\mathbf{D} $\langle \cdot \rangle$	

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